CD74FCT244, CD74FCT244AT BICMOS OCTAL BUFFERS/LINE DRIVERS WITH 3-STATE OUTPUTS

CD74FCT244...E, M, OR SM PACKAGE CD74FCT244AT...E OR M PACKAGE

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- BiCMOS Technology With Low Quiescent Power
- Buffered Inputs
- Noninverted Outputs
- Input/Output Isolation From V_{CC}
- Controlled Output Edge Rates
- 64-mA Output Sink Current
- Output Voltage Swing Limited to 3.7 V
- SCR Latch-Up-Resistant BiCMOS Process and Circuit Design

(TOP VIEW) 10E 1A1 **∏** 2 2Y4 [3 18 1Y1 1A2 🛮 4 17 2A4 2Y3 🛮 5 16**∏** 1Y2 1A3 ∏ 15 2A3 2Y2 🛮 7 14 1 1Y3 13 1 2A2 1A4 **∏** 8 12 1Y4 2Y1 🛮 9 GND ∏ 11 **∏** 2A1

description/ordering information

The CD74FCT244 and CD74FCT244AT are octal buffer/line drivers with 3-state outputs using a

small-geometry BiCMOS technology. The output stages are a combination of bipolar and CMOS transistors that limit the output high level to two diode drops below V_{CC} . This resultant lowering of output swing (0 V to 3.7 V) reduces the power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 mA.

These devices are organized as two 4-bit buffers/line drivers with separate active-low output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PACI	KAGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – E	Tube	CD74FCT244E	CD74FCT244E
	SOIC - M	Tube	CD74FCT244M	7450504414
	301C - W	Tape and reel	CD74FCT244M96	74FC1244WI
0°C to 70°C	SSOP - SM	Tape and reel	CD74FCT244SM96	FCT244SM
	PDIP – E	Tube	CD74FCT244ATE	CD74FCT244ATE
	SOIC - M	Tube	CD74FCT244ATM	745072444714
	301C - W	Tape and reel	CD74FCT244ATM96	CD74FCT244E 74FCT244M FCT244SM

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each buffer/driver)

INP	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	X	Z

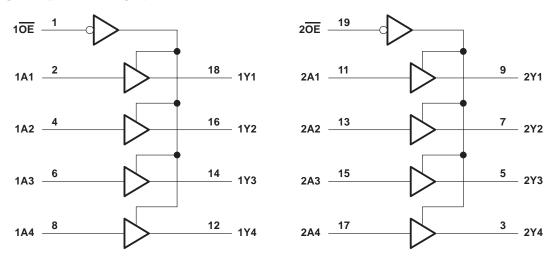


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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

DC supply voltage range, V _{CC}		–0.5 V to 6 V
DC input clamp current, I_{IK} ($V_I < -0.5 \text{ V}$)		–20 mA
DC output clamp current, I_{OK} ($V_O < -0.5 \text{ V}$)		–50 mA
DC output sink current per output pin, IOL		70 mA
DC output source current per output pin, IOH .		–30 mA
Continuous current through V _{CC} , I _{CC}		
Continuous current through GND		528 mA
Package thermal impedance, θ_{JA} (see Note 1):	E package	69°C/W
	M package	58°C/W
	SM package	70°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

		MIN	MAX	UNIT
VCC	Supply voltage	4.75	5.25	V
VIH	High-level input voltage	2		V
V_{IL}	Low-level input voltage		0.8	V
VI	Input voltage	0	VCC	V
Vo	Output voltage	0	VCC	V
ІОН	High-level output current		-15	mA
loL	Low-level output current		64	mA
Δt/Δν	Input transition rise or fall rate (slew rate)		10	ns/V
TA	Operating free-air temperature	0	70	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Voc	T _A = 2	25°C	MIN	MAX	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	MAX	IVIIIV	IVIAA	UNIT
VIK	$I_{I} = -18 \text{ mA}$	4.75 V		-1.2		-1.2	V
Voн	$I_{OH} = -15 \text{ mA}$	4.75 V	2.4		2.4		V
V _{OL}	I _{OL} = 64 mA	4.75 V		0.55		0.55	V
lį	$V_I = V_{CC}$ or GND	5.25 V		±0.1		±1	μΑ
loz	$V_O = V_{CC}$ or GND	5.25 V		±0.5		±10	μΑ
los†	$V_I = V_{CC}$ or GND, $V_O = 0$	5.25 V	-60		-60		mA
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.25 V		8		80	μΑ
Δl _{CC} ‡	One input at 3.4 V, Other inputs at V _{CC} or GND	5.25 V		1.6		1.6	mA
C _i	$V_I = V_{CC}$ or GND			10		10	pF
Co	$V_O = V_{CC}$ or GND			15		15	pF

Thot more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.25 V (unless otherwise noted) (see Figure 1)

			CD74	FCT244		CD74FCT244AT			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 25°C	MIN	MAX	T _A = 25°C	MIN	MAX	UNIT
	(0.)	(001101)	TYP	IVIIIN	IVIAA	TYP	IVIIIN	WAA	
t _{pd}	А	Υ	4.5	1.5	6.5	3.8	1.5	5.3	ns
t _{en}	ŌĒ	Υ	6	1.5	8	4.8	1.5	6.5	ns
^t dis	ŌĒ	Υ	5	1.5	7	4.5	1.5	5.8	ns

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		1		V
VOH(V)	Quiet output, minimum dynamic VOH		0.5		V
VIH(D)	High-level dynamic input voltage	2			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V

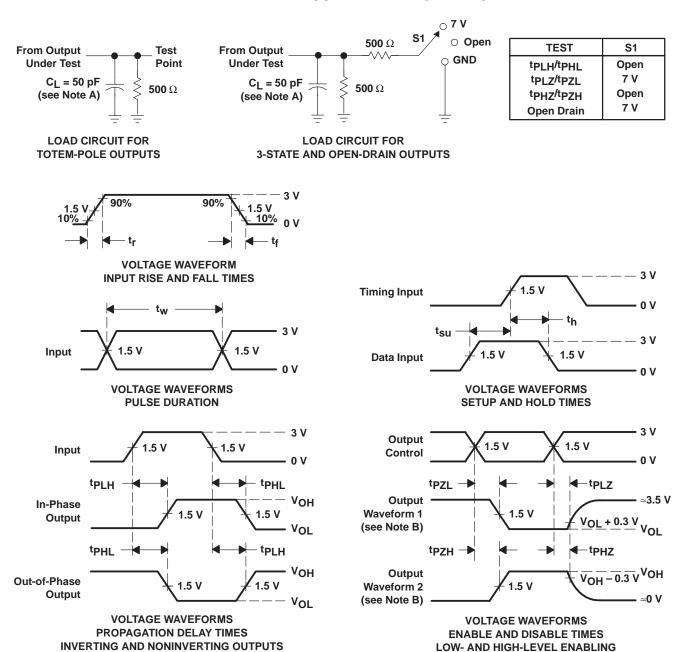
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1 MHz	35	pF



[‡] This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or VCC.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, t_f and $t_f = 2.5$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms







11-Jan-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74FCT244ATE	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	CD74FCT244ATE	Samples
CD74FCT244ATM	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT244ATM	Samples
CD74FCT244ATM96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT244ATM	Samples
CD74FCT244ATMG4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT244ATM	Samples
CD74FCT244E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	CD74FCT244E	Samples
CD74FCT244M	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT244M	Samples
CD74FCT244M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	74FCT244M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

11-Jan-2021

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	<u> </u>
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74FCT244ATM96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74FCT244M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74FCT244ATM96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74FCT244M96	SOIC	DW	20	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74FCT244ATE	N	PDIP	20	20	506	13.97	11230	4.32
CD74FCT244ATM	DW	SOIC	20	25	507	12.83	5080	6.6
CD74FCT244ATMG4	DW	SOIC	20	25	507	12.83	5080	6.6
CD74FCT244E	N	PDIP	20	20	506	13.97	11230	4.32
CD74FCT244M	DW	SOIC	20	25	507	12.83	5080	6.6

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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